DATA SHEET

74F242
Quad transceiver, inverting (3-State)
74F243
Quad transceiver (3-State)

Product specification

1990 Aug 31

IC15 Data Handbook

Philips
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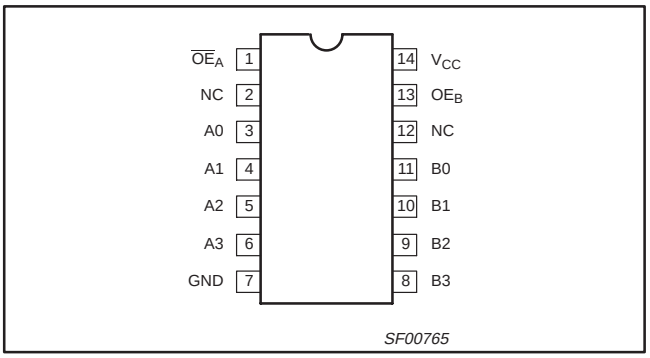
Transceivers 74F242/74F243

74F242 Quad Transceiver, Inverting (3-State)
74F243 Quad Transceiver (3-State)

PIN CONFIGURATION



TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F242	4.3ns	31.2mA
74F243	4.0ns	66mA

ORDERING INFORMATION

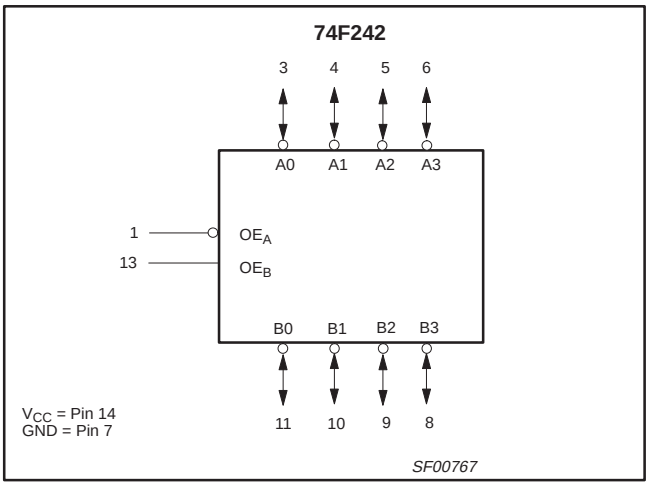
DESCRIPTION	COMMERCIAL RANGE V_{CC} = 5V ±10%, T_{amb} = 0°C to +70°C	PKG DWG #
14-pin plastic DIP	N74F242N, N74F243N	SOT27-1
14-pin plastic SO	N74F242D, N74F243D	SOT108-1

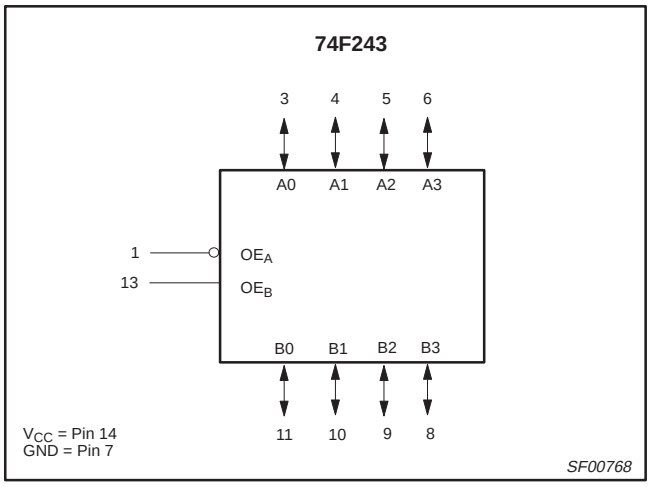
INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
An, Bn	Data inputs (74F242)	3.5/1.67	70µA/1.0mA
An, Bn	Data inputs (74F243)	3.5/2.67	70µA/1.6mA
$\overline{OE}_A$	Output enable input (active Low)	1.0/1.67	20µA/1.0mA
OE_B	Output enable input	1.0/1.67	20µA/1.0mA
An, Bn	Data outputs	750/106.7	15mA/64mA

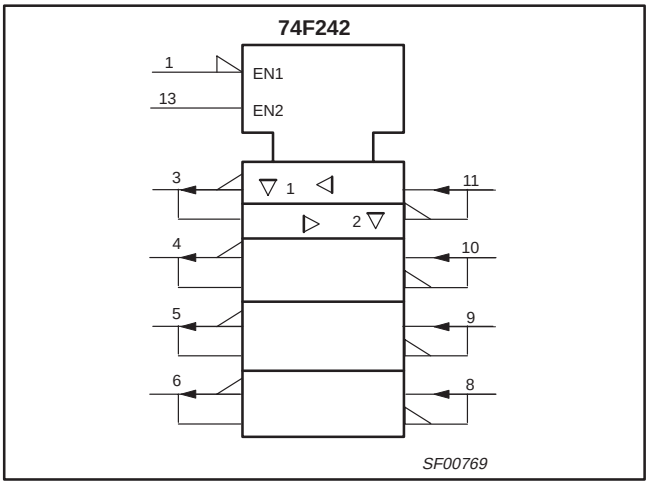
NOTE: One (1.0) FAST unit load is defined as: 20µA in the High state and 0.6mA in the Low state.

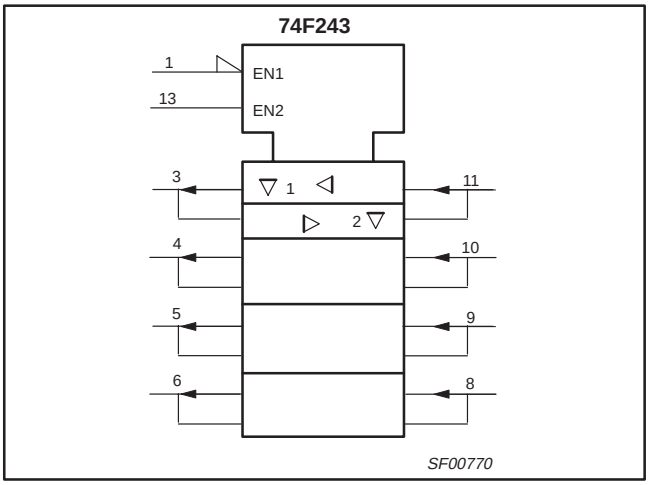
LOGIC SYMBOLS

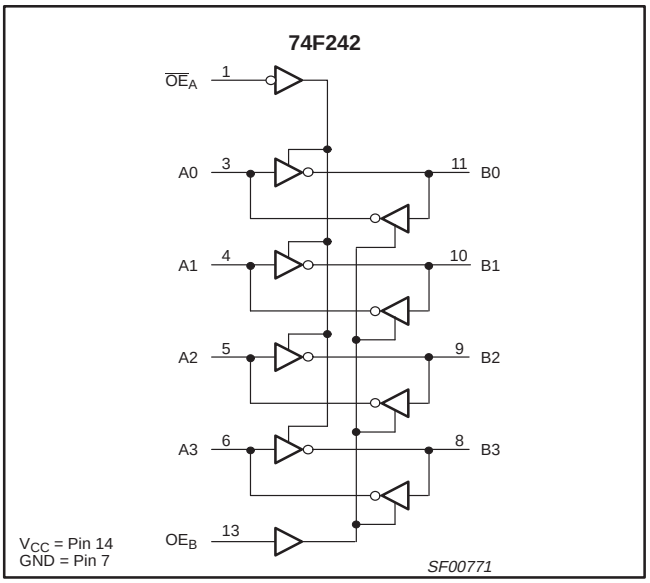


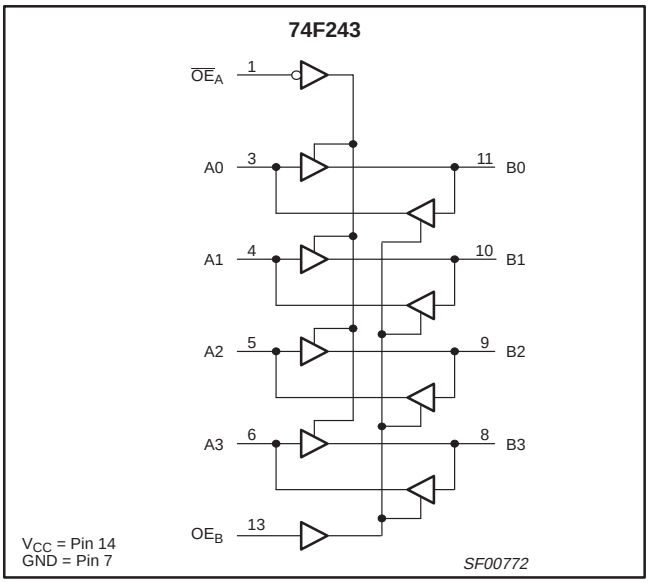


LOGIC SYMBOLS (IEEE/IEC)









LOGIC DIAGRAMS

FUNCTION TABLE, 74F242

INPUTS		OUTPUTS	
$\overline{OE}_A$	OE_B	An	Bn
L	L	INPUT	B=$\overline{A}$
H	L	Z	Z
L	H	a	a
H	H	A=$\overline{B}$	INPUT

FUNCTION TABLE, 74F243

INPUTS		OUTPUTS	
$\overline{OE}_A$	OE_B	An	Bn
L	L	INPUT	B=A
H	L	Z	Z
L	H	a	a
H	H	A=B	INPUT

H = High voltage level
L = Low voltage level
Z = High impedance “off” state
a = This condition is not allowed due to excessive currents

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device.
Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V_{CC}	Supply voltage	–0.5 to +7.0	V
V_{IN}	Input voltage	–0.5 to +7.0	V
I_{IN}	Input current	–30 to +5	mA
V_{OUT}	Voltage applied to output in High output state	–0.5 to V_{CC}	V
I_{OUT}	Current applied to output in Low output state	128	mA
T_{amb}	Operating free-air temperature range	0 to +70	°C
T_{stg}	Storage temperature	–65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS			UNIT
		MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5.0	5.5	V
V_{IH}	High-level input voltage	2.0			V
V_{IL}	Low-level input voltage			0.8	V
I_{IK}	Input clamp current			–18	mA
I_{OH}	High-level output current			–15	mA
I_{OL}	Low-level output current			64	mA
T_{amb}	Operating free-air temperature range	0		70	°C

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMETER		TEST CONDITIONS[1]			LIMITS			UNIT
						MIN	TYP[2]	MAX	
V_{OH}	High-level output voltage		V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN	I_{OH} = –3mA	±10%V_{CC}	2.4			V
					±5%V_{CC}	2.7	3.3		
			V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN	I_{OL} = –15mA	±10%V_{CC}	2.0	3.2		V
					±5%V_{CC}	2.0	3.1		
V_{OL}	Low-level output voltage		V_{CC} = MIN, V_{IL} = MAX, V_{IH} = MIN	I_{OH}=MAX	±10%V_{CC}			0.55	V
					±5%V_{CC}		0.42	0.55	
V_{IK}	Input clamp voltage		V_{CC} = MIN, I_I = I_{IK}				–0.73	–1.2	V
I_I	Input current at maximum input voltage	A0–A3, B0–B3	V_{CC} = MAX, V_I = 5.5V					1	mA
		$\overline{OE}_A$, OE_B	V_{CC} = MAX, V_I = 7.0V					100	µA
I_{IH}	High-level input current	OE_A, OE_B only	V_{CC} = MAX, VI = 2.7V					20	µA
I_{IL}	Low-level input current		V_{CC} = MAX, VI = 0.5V					–1	mA
I_{IH}+I_{OZH}	Off-state output current High-level voltage applied		V_{CC} = MAX, V_O = 2.7V					70	µA
I_{IL}+I_{OZL}	Off-state output current Low-level voltage applied	74F242	V_{CC} = MAX, V_O = 0.5V					–1.0	mA
		74F243						–1.6	
I_{OS}	Short-circuit output current[3]		V_{CC} = MAX			–100		–225	mA
I_{CC}	Supply current (total)	74F242	I_{CCH}	V_{CC} = MAX			22	35	mA
			I_{CCL}				40	55	mA
			I_{CCZ}				32	45	mA
		74F243	I_{CCH}	V_{CC} = MAX			64	80	mA
			I_{CCL}				64	90	mA
			I_{CCZ}				71	90	mA

NOTES:

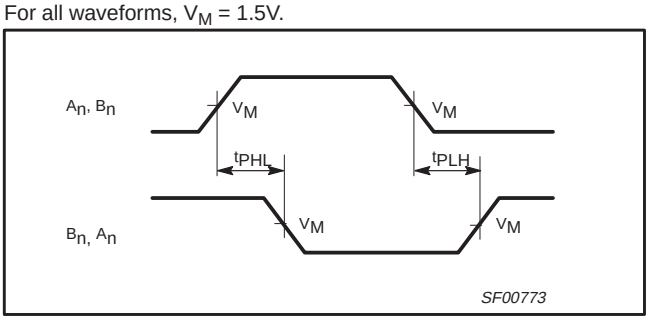
1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.
2. All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
3. Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

AC ELECTRICAL CHARACTERISTICS

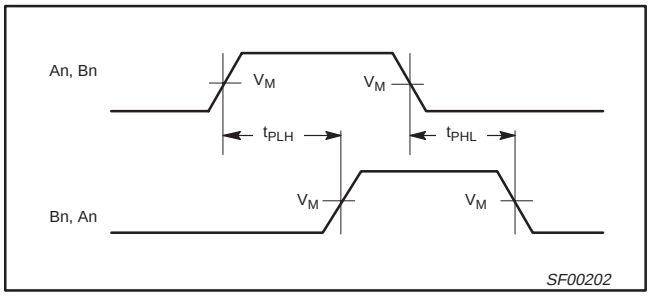
SYMBOL	PARAMETER		TEST CONDITION	LIMITS					UNIT
				V_{CC} = +5V T_{amb} = +25°C C_L = 50pF, R_L = 500Ω			V_{CC} = +5V ± 10% T_{amb} = 0°C to +70°C C_L = 50pF, R_L = 500Ω		
				MIN	TYP	MAX	MIN	MAX	
t_{PLH} t_{PHL}	Propagation delay An, Bn to Bn, An	74F242	Waveform NO TAG	2.5 2.0	3.5 3.0	6.0 4.5	2.5 2.0	7.0 4.5	ns
t_{PZH} t_{PZL}	Output Enable time to High or Low level		Waveform 3 Waveform 4	3.0 3.5	4.0 6.5	7.0 9.0	3.0 3.5	8.0 10.5	ns
t_{PHZ} t_{PLZ}	Output Disable time from High or Low level		Waveform 3 Waveform 4	3.5 3.5	5.5 6.0	8.5 9.5	3.5 3.5	9.0 11.0	ns
t_{PLH} t_{PHL}	Propagation delay An, Bn to Bn, An	74F243	Waveform 2	2.5 2.5	4.0 4.0	5.2 5.2	2.0 2.0	6.2 6.5	ns
t_{PZH} t_{PZL}	Output Enable time to High or Low level		Waveform 3 Waveform 4	2.0 2.0	4.5 5.0	5.7 7.5	2.0 2.0	6.7 8.5	ns
t_{PHZ} t_{PLZ}	Output Disable time from High or Low level		Waveform 3 Waveform 4	2.0 2.0	4.0 4.5	6.0 6.0	2.0 2.0	7.0 7.0	ns

AC WAVEFORMS

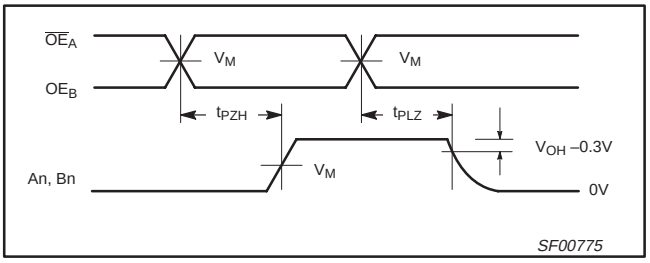
For all waveforms, V_M = 1.5V.



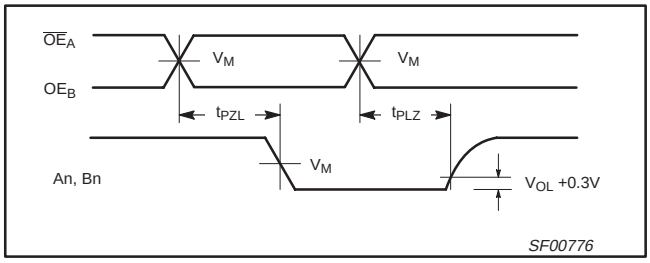
Waveform 1. For Inverting Outputs



Waveform 2. For Non-Inverting Outputs

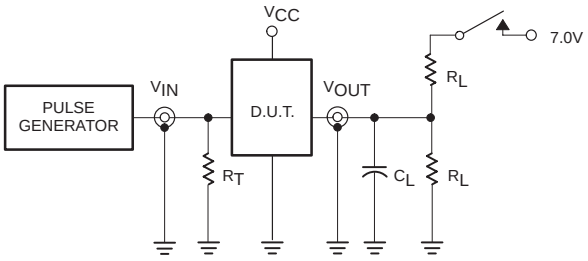


Waveform 3. 3-State Output Enable Time to High Level and Output Disable Time from High Level

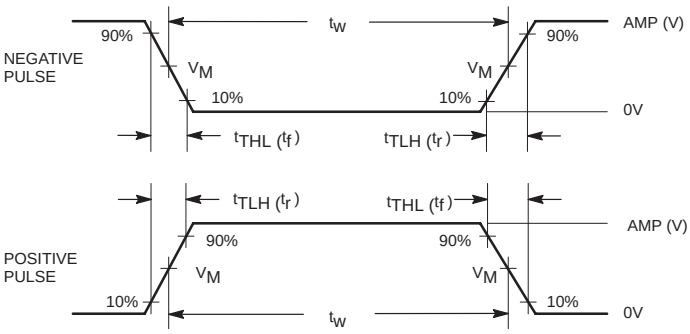


Waveform 4. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

TEST CIRCUIT AND WAVEFORMS



Test Circuit for 3-State Outputs



Input Pulse Definition

SWITCH POSITION

TEST	SWITCH
t_{PLZ}	closed
t_{PZL}	closed
All other	open

DEFINITIONS:

R_L = Load resistor; see AC electrical characteristics for value.

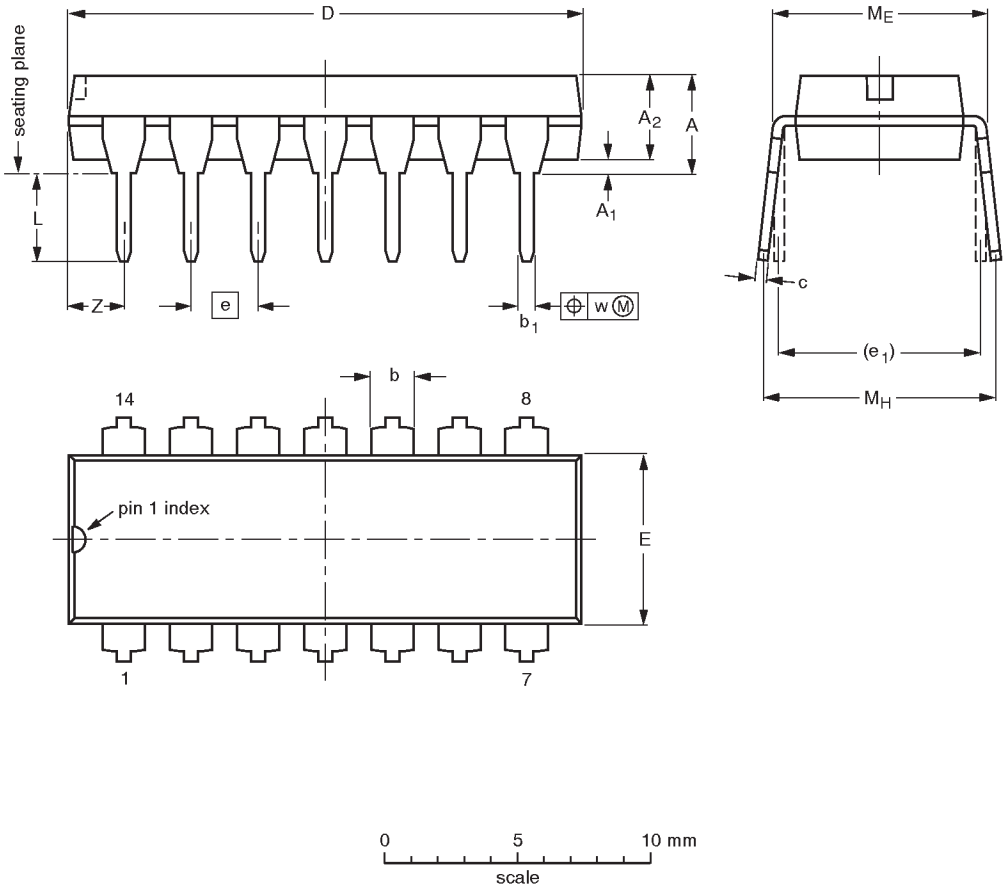
C_L = Load capacitance includes jig and probe capacitance; see AC electrical characteristics for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

family	INPUT PULSE REQUIREMENTS					
	amplitude	V_M	rep. rate	t_w	t_{TLH}	t_{THL}
74F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns

SF00777

DIP14: plastic dual in-line package; 14 leads (300 mil) SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

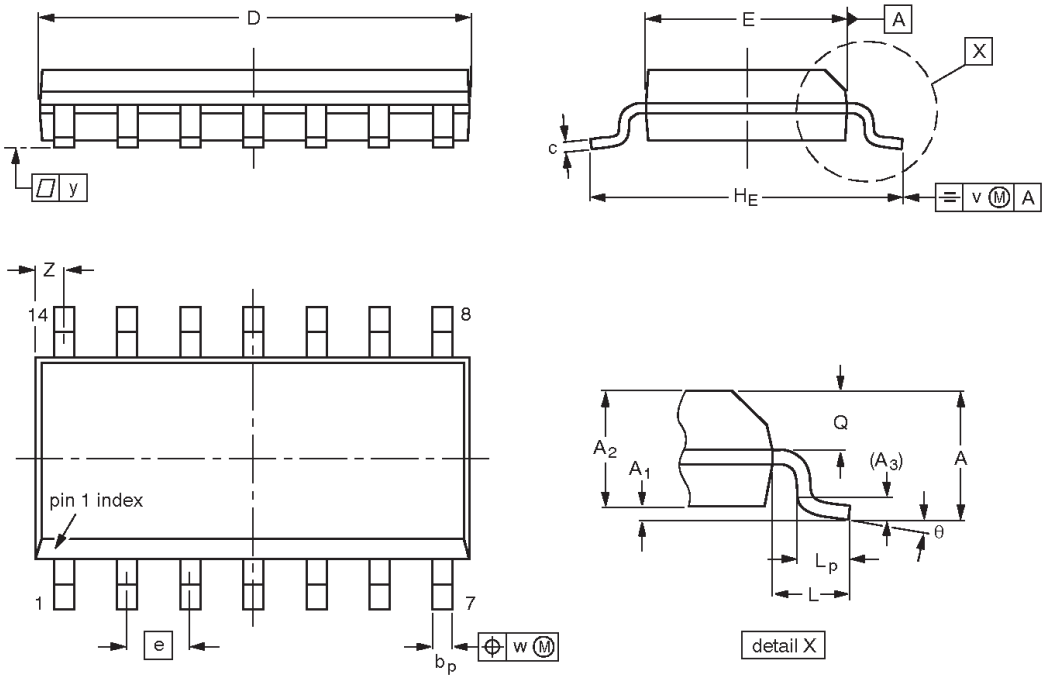
UNIT	A max.	A_1 min.	A_2 max.	b	b_1	c	D (1)	E (1)	e	e_1	L	M_E	M_H	w	Z (1) max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

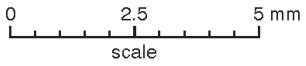
Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT27-1	050G04	MO-001AA				~~92-11-17~~ 95-03-11

SO14: plastic small outline package; 14 leads; body width 3.9 mm SOT108-1





DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8^o 0^o
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT108-1	076E06S	MS-012AB				~~95-01-23~~ 97-05-22

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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